

Photo Reflective Sensor

0-04-04-22 Preliminary

Module No.: RS-06WD

1. General Description

RS-06WD reflective sensor combines a GaAs infrared light emitting diode with a high sensitive phototransistor in a mini package.

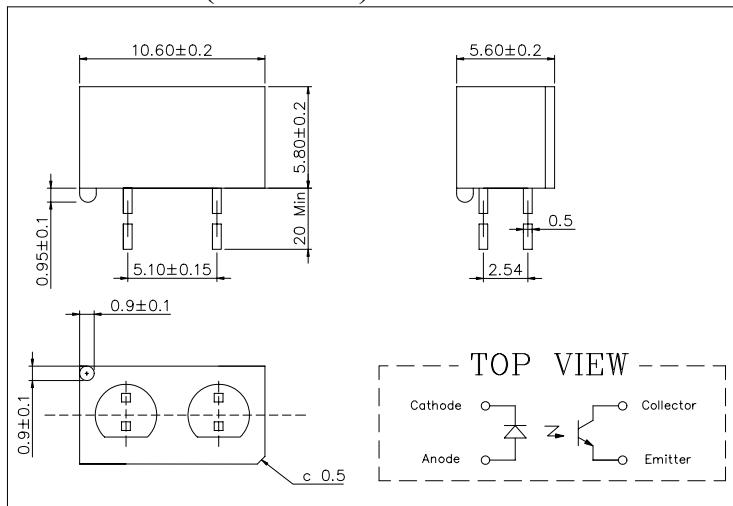
2. Features

- Compact
- High performance
- High speed response
- Easy to mount on P.C.B.
- Widely applicable

3. Applications

- Timing sensors
- Edge sensors
- Micro floppy disc drives
- Level sensors of liquid

Dimensions (Unit: mm)



4. Maximum Ratings

(Ta=25°C)				
	Item	Symbol	Rating	Unit
Input	Power Dissipation	PD	100	mW
	Reverse Voltage	VR	5	V
	Forward Current	IF	50	mA
	Pulse Forward Current *1	IFP	1	A
Output	Collector Power Dissipation	Pc	100	mW
	Collector Current	Ic	20	mA
	C-E Voltage	VCEO	30	V
	E-C Voltage	VECO	5	V
Operating Temperature		Topr	-10 ~ +65	°C
Storage Temperature		Tstg	-20 ~ +85	°C
Soldering Temperature *2		Tsol	260	°C

*1. tw=100μsec. T=10msec.

*2. At the position of 2mm from the bottom of the package within 5 seconds.

5. Electro-optical Characteristics

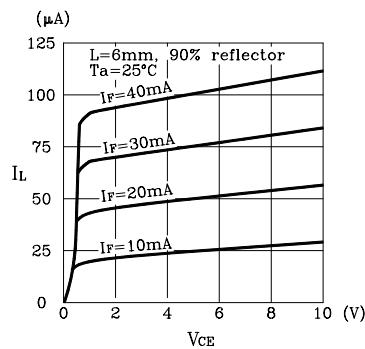
(Ta=25°C)

	Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Input	Forward Voltage	VF	IF=20mA		1.2	1.6	V
	Reverse Current	IR	VR=5V			10	μA
	Capacitance	Ct	V=0V, f=1kHz		25		pF
	Peak Wavelength	λp			940		nm
Output	Collector Dark Current	ICEO	VCE=20V			0.1	μA
	Light Current	IL	VCE=5V, IF=20mA	50			μA
	Leakage Current	ICEOD	VCE=5V, IF=10mA			1	μA
Switching Speeds	Rise Time	tr	Vcc=5V, Ic=1mA,		15		μsec
	Fall Time	tf	RL=1kΩ		15		μsec

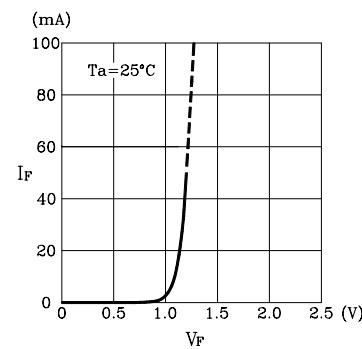
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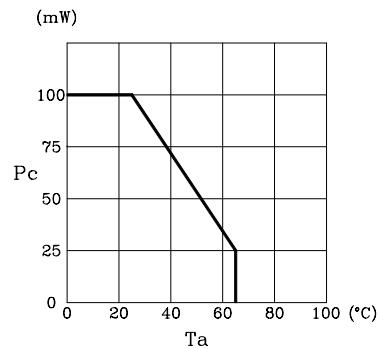
Light Current vs
Collector-Emitter Voltage



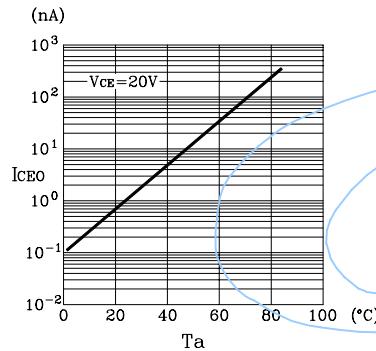
Forward Current vs
Forward Voltage



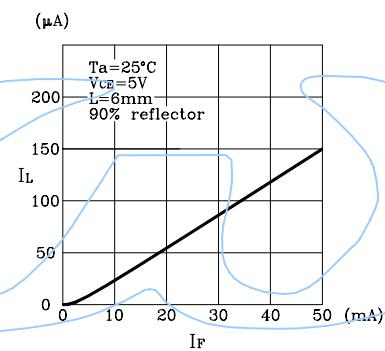
Power Dissipation vs
Ambient Temperature



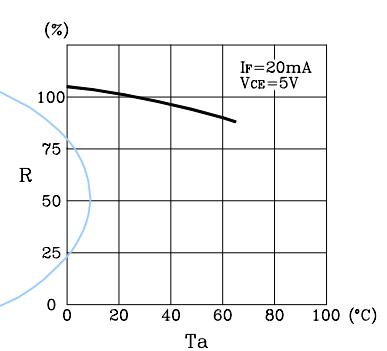
Dark Current vs
Ambient Temperature



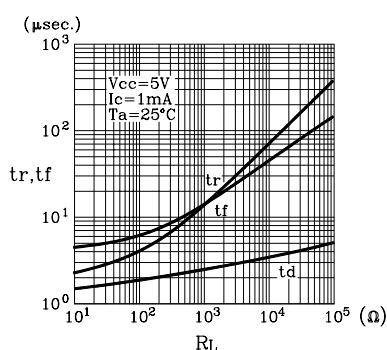
Light Current vs
Forward Current



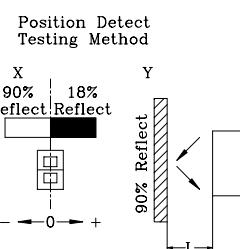
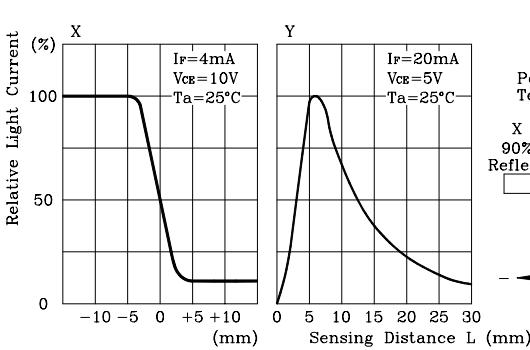
Relative Light Current vs
Ambient Temperature



Response Time vs
Load Resistance



Position Detect
Characteristics



Response Time Test Conditions

